Wide Vin 50V Non-synchronous Boost/Flyback/SEPIC Controller

FEATURES

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
  - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level H2
  - Device CDM ESD Classification Level C3B
- Wide Input Voltage Range: 3.1V-50V
- Low Shutdown Current 3.9uA
- Low Quiescent Operating Current: 415uA
- +/- 1.5% Feedback Reference Voltage
- Adjustable Switching Frequency: 100KHz to 2.2MHz
- Integrated Frequency Dither for EMI Mitigation
- External Frequency Synchronic
- External Compensation
- Pulse Skipping Mode
- Supports additional Slope Compensation
- 14ms Internal Soft-start Time
- Integrated Protection Feature
  - Constant Peak-Current Protection Threshold Over Input Voltage
  - Output Overvoltage Protection
  - Adjustable Under-voltage Lockout
  - Hiccup Over Load Protection
  - Thermal Shutdown Protection:165°C
- MSOP-10L(3mm*3mm)

DESCRIPTION

The SCT81621 device is a wide input, non-synchronous boost controller. The device can be used in Boost, SEPIC and Flyback converters.

The switching frequency of the SCT81621 device can be adjusted to any value between 100kHz and 2.2MHz by using a single external resistor or by synchronizing it to an external clock. Current mode control provides superior bandwidth and transient response in addition to cycle-by-cycle current limiting. Current limit is adjustable through an external resistor.

The SCT81621 is an Electromagnetic Interference (EMI) friendly controller with implementing optimized design for EMI reduction. The SCT81621 features Frequency Spread Spectrum (FSS) with ±6% jittering span of the switching frequency and modulation rate 1/512 of switching frequency to reduce the conducted EMI.

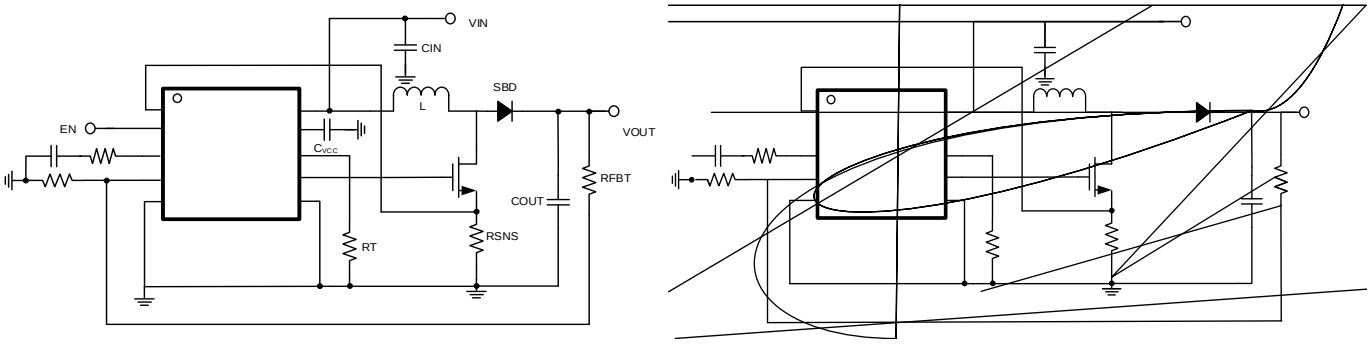
The SCT81621 device has built-in protection features such as thermal shutdown, short-circuit protection and overvoltage protection. Power-saving shutdown mode reduces the total supply current to 3.9 µA. Integrated current slope compensation simplifies the design and, if needed for specific applications, can be increased using a single resistor.

The device is available in a MSOP-10L(3mm*3mm) Package.

APPLICATIONS

- Multi-output Flyback
- LED Bias Supply
- Portable Speaker Supply
- Battery Powered Boost/Flyback/SEPIC application

TYPICAL APPLICATION



REVISION HISTORY

Figure 9 and 10.

DEVICE ORDER INFORMATION

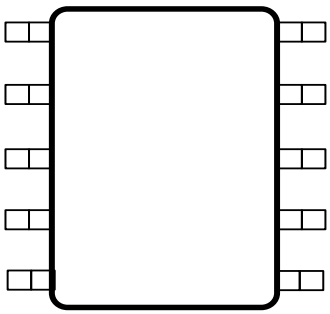
ORDERABLE DEVICE	PACKAGING TYPE	STANDARD PACK QTY	PACKAGE MARKING	PINS	PACKAGE DISCRIPTION	MSL
SCT81621MRDR	Tape & Reel	4000	1621	10	10-Lead 3mm×3mm Plastic MSOP	3

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature unless otherwise noted(1)

DESCRIPTION	MIN	MAX	UNIT
VIN, UVLO_EN	-0.3	62	V
VCC, DR (DC voltage)	-0.3	6.6	V
VCC, DR (Transient for <20ns)	-1	7.0	V
ISEN, COMP, FB, FA/SYNC/SD	-0.3	5.5	V
Peak Driver Output Current		1(2)	A
Junction temperature(2)	-40	150	C
Storage temperature T_{STG}	-65	150	C

PIN CONFIGURATION



Top View: 10-Lead Plastic MSOP 3mmx3mm

(1) Stresses beyond those listed under Absolute Maximum Rating may cause device permanent damage. The device is not guaranteed to function outside of its Recommended Operation Conditions.
(2) Guaranteed by design, not tested in productions.
(3) The IC includes over temperature protection to protect the device during overload conditions. Junction temperature will exceed 170°C when over temperature protection is active. Continuous operation above the specified maximum operating junction temperature will reduce lifetime.

PIN FUNCTIONS

NAME	NO.	DESCRIPTION
ISEN	1	Current sense input pin. Connect to the positive side of the current sense resistor through a short path.
UVLO_EN	2	Undervoltage lockout programming pin. The converter start-up and shutdown levels can be programmed by connecting this pin to the supply voltage through a resistor divider. This pin must not be left floating. Connect to VIN pin if not used.
COMP	3	Output of the internal transconductance error amplifier. Connect the loop compensation components between this pin and ground.
FB	4	Inverting input of the error amplifier. Connect a voltage divider from the output to this pin to set output voltage. The device regulates FB voltage to the internal reference value of 1.275V typical.
AGND	5	Analog ground pin.

PIN FUNCTIONS (continued)

NAME	NO.	DESCRIPTION
FA/SYNC/SD	6	Switching frequency setting pin. The switching frequency is programmed by a single resistor between this pin and AGND. The internal clock can be synchronized to an external clock. A high level on this will then draw 3.9 µA from the supply typically.
PGND	7	Power ground pin.
DR	8	N-channel MOSFET gate drive output. Connect directly to the gate of the N-channel MOSFET through a short, low inductance path.
VCC	9	Output of the internal VCC regulator and supply voltage input of the MOSFET driver. Connect a ceramic bypass capacitor from this pin to PGND.
VIN	10	Power supply input pin Connect a ceramic bypass capacitor from this pin to PGND.

RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range unless otherwise noted

PARAMETER	DEFINITION	MIN	MAX	UNIT
V_{IN}	Input voltage range	3.1	50	V
V_{CC}	VCC voltage range	3.1	6.1	V
T_J	Operating junction temperature	-40	125	°C

ELECTRICAL CHARACTERISTICS

V_{IN}=12V, T_J=-40°C~125°C, typical values are tested under 25°C.

SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
Power Supply and Output						
V_{IN}	Operating input voltage		3.1		50	V
V_{IN_UVLO}	Input UVLO Hysteresis	V_{IN} rising		2.8 160		V mV
I_{SD}	Shutdown current	$V_{FA/SYCN/SD}$=5V or V_{UVLO_EN}=0		3.9	8	uA
I_Q	Quiescent current from VIN	no load, no switching, V_{FB}=2V		415		uA
I_{SUPPLY}(1)	Supply Current	$R_{FA/SYNC/SD}$ switching, no load and without external MOSFET		2		mA
VCC Power						
V_{CC}	Internal linear regulator	VIN>7V		6.1		V
V_{CC_uvlo}				2.85		V
$V_{CC\_uvlo\_hys}$				75		mV
IV_{CC}	VCC Sourcing current limit		20	70		mA
UVLO/EN						
$V_{UVLOSEN}$	Under voltage Lockout reference voltage	V_{UVLO} ramping up	1.34	1.42	1.5	V
I_{UVLO}	UVLO source current		3	4.75	6.5	uA
V_{UVLOSD}	UVLO shut down voltage	V_{UVLO} ramping down	0.55	0.65	0.75	V
Reference and Control Loop						
V_{REF}	Reference voltage of FB		1.256	1.275	1.294	V
I_{FB}	FB pin leakage current	V_{FB}=1V			100	nA
G_{EA}	Error amplifier trans-conductance	V_{COMP}=1.5V	190	390	590	uS
I_{COMP_SRC}	Error amplifier maximum source current	V_{FB}=V_{REF}-200mV, V_{COMP}=1.5V	340	560	710	

ELECTRICAL CHARACTERISTICS (continued)

V_{IN}=12V, T_J=-40°C~125°C, typical values are tested under 25°C.

SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
C_{HICCUP}	Hiccup mode off-time after activation	Clock cycles with no switching followed by SS release		32768		cycles
Soft start						
T_{SS}	Soft-start Time			14		ms
Switching Frequency						
F_{SW}	Switching frequency	$R_{FA/SYNC/SD}$=47.5	345	400	455	kHz
F_{SS}	Frequency Spread Range			6		%
$_{SYN\_HI}$	Threshold for Synchronization on FA/SYNC/SD pin	Synchronization voltage rising		1.27	1.45	V
$_{SYN\_LO}$		Synchronization voltage falling	0.58	0.68		V
D_{MAX}	Maximum Duty Cycle	$R_{FA/SYNC/SD}$=47.5	85	91		%
t_{ON_MIN}	Minimum on-time	Fsw=400kHz		250		ns
V_{SD_HI}	Shutdown signal threshold on FA/SYNC/SD pin	Shutdown voltage rising		1.27	1.45	V
V_{SD_LO}		Shutdown voltage falling	0.57	0.68		V
I_{SD_LKG}	FA/SYNC/SD pin Leakage	V_{SD}=5V			1	uA

TYPICAL CHARACTERISTICS

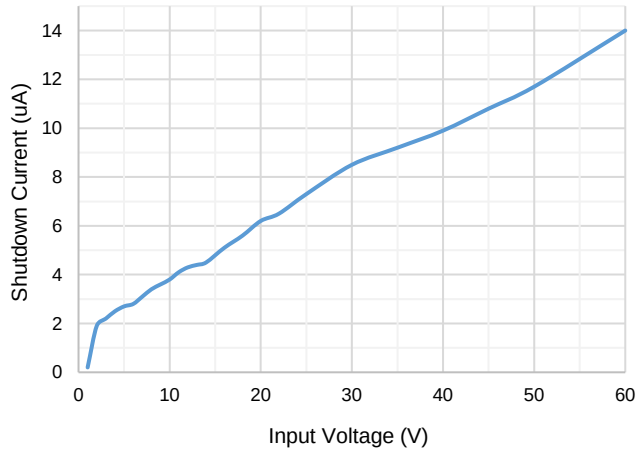


Figure 1. I_{SD} vs. Input Voltage

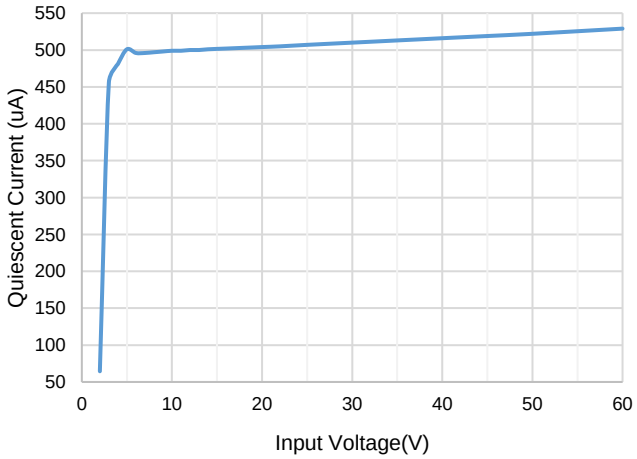


Figure 2. I_Q vs. Input Voltage

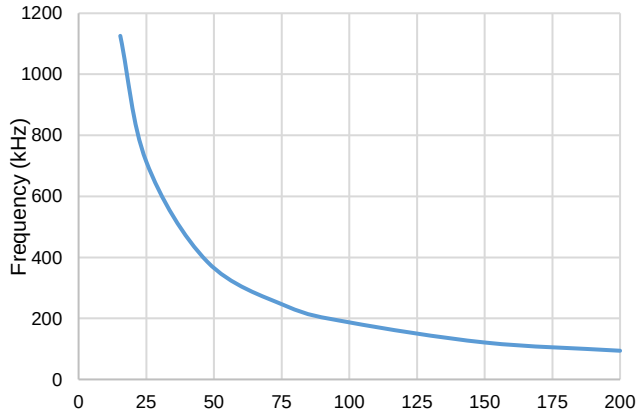


Figure 3. Switching Frequency vs. RT

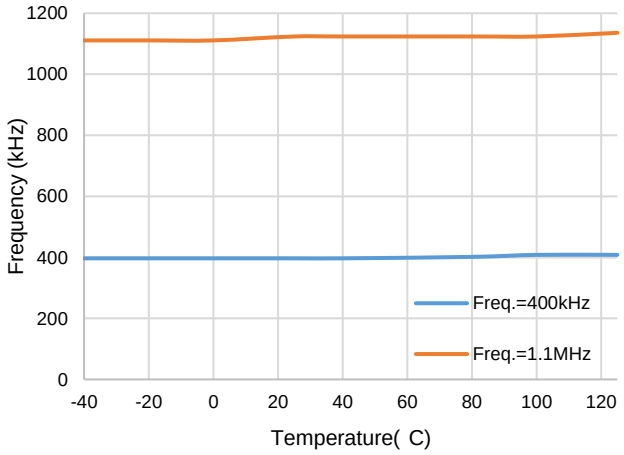


Figure 4. Switching Frequency vs. Temperature

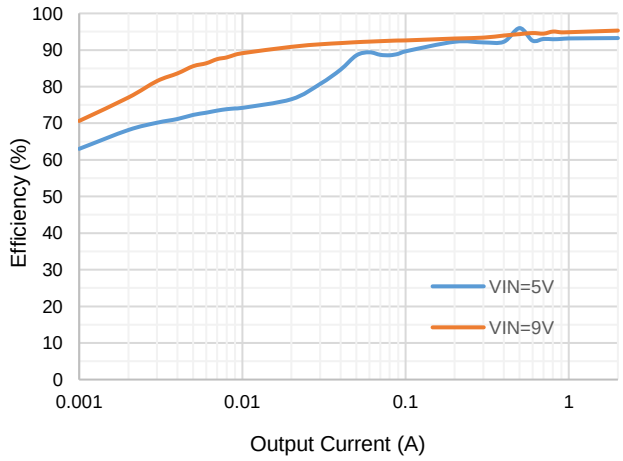


Figure 5. Efficiency vs. Load Current, Boost, V_{OUT}=12V

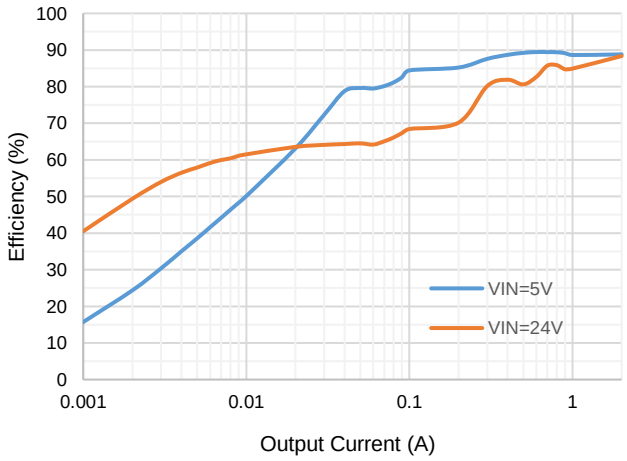


Figure 6. Efficiency vs. Load Current, SEPIC, V_{OUT}=12V

TYPICAL CHARACTERISTICS

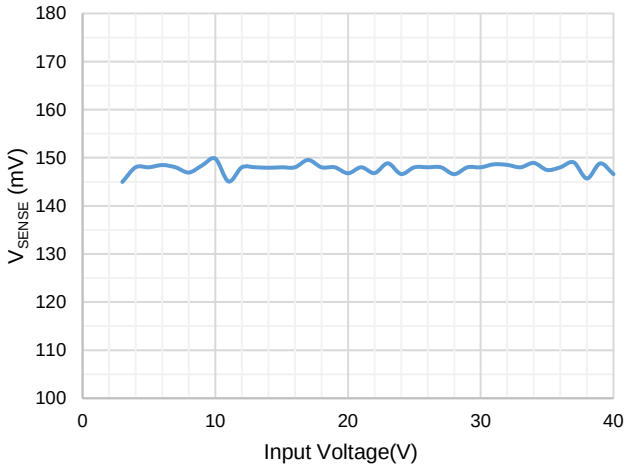


Figure 7. Current Sense Threshold vs. Input Voltage

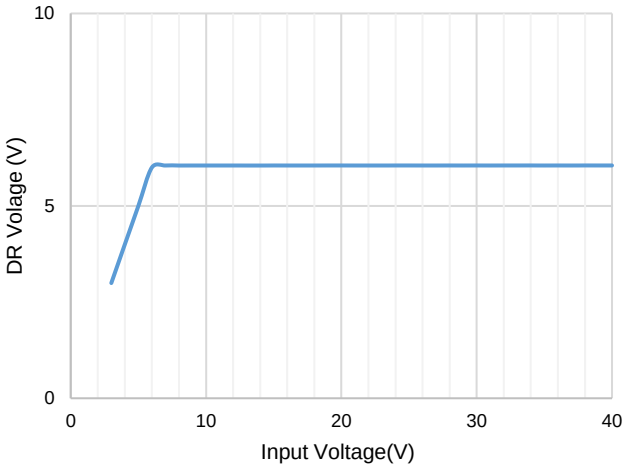


Figure 8. DR Volage vs. Input Voltage

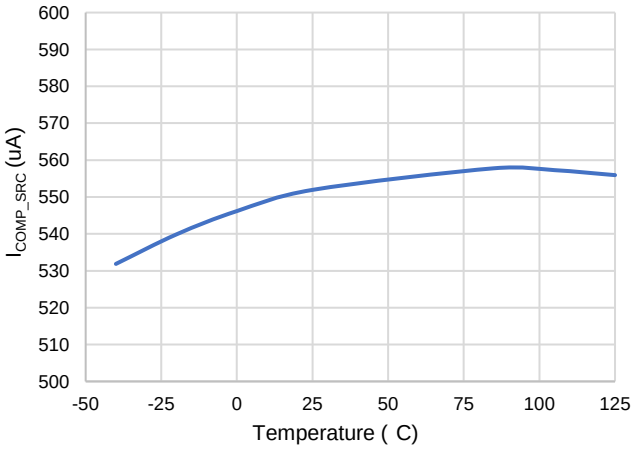


Figure 9. COMP Source Current vs. Temperature

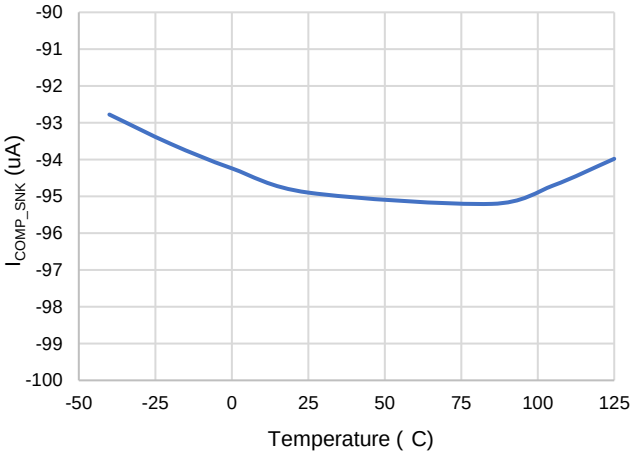


Figure 10. COMP Sink Current vs. Temperature

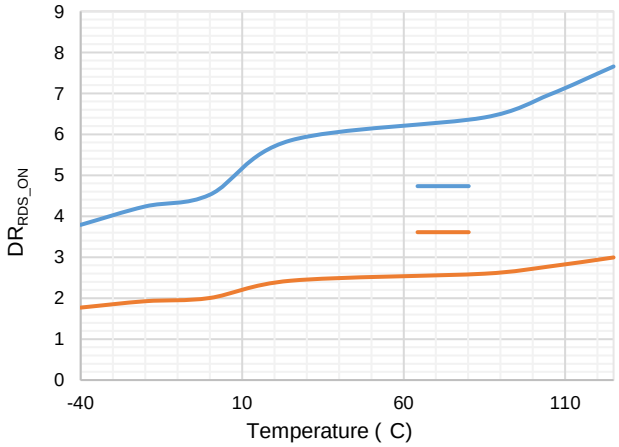


Figure 11. DR Resistance vs. Temperature

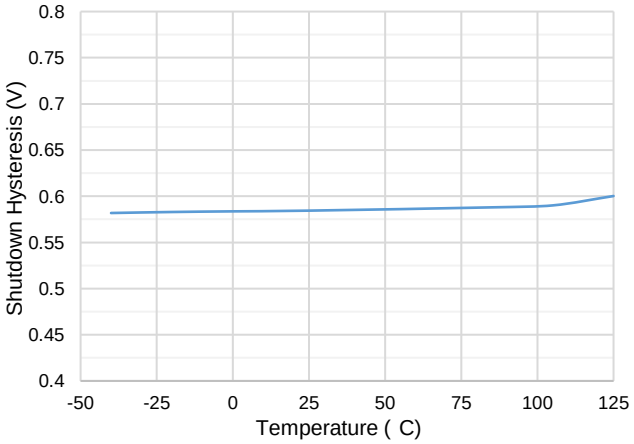


Figure 12. Shutdown Threshold Hysteresis vs. Temperature

FUNCTIONAL BLOCK DIAGRAM

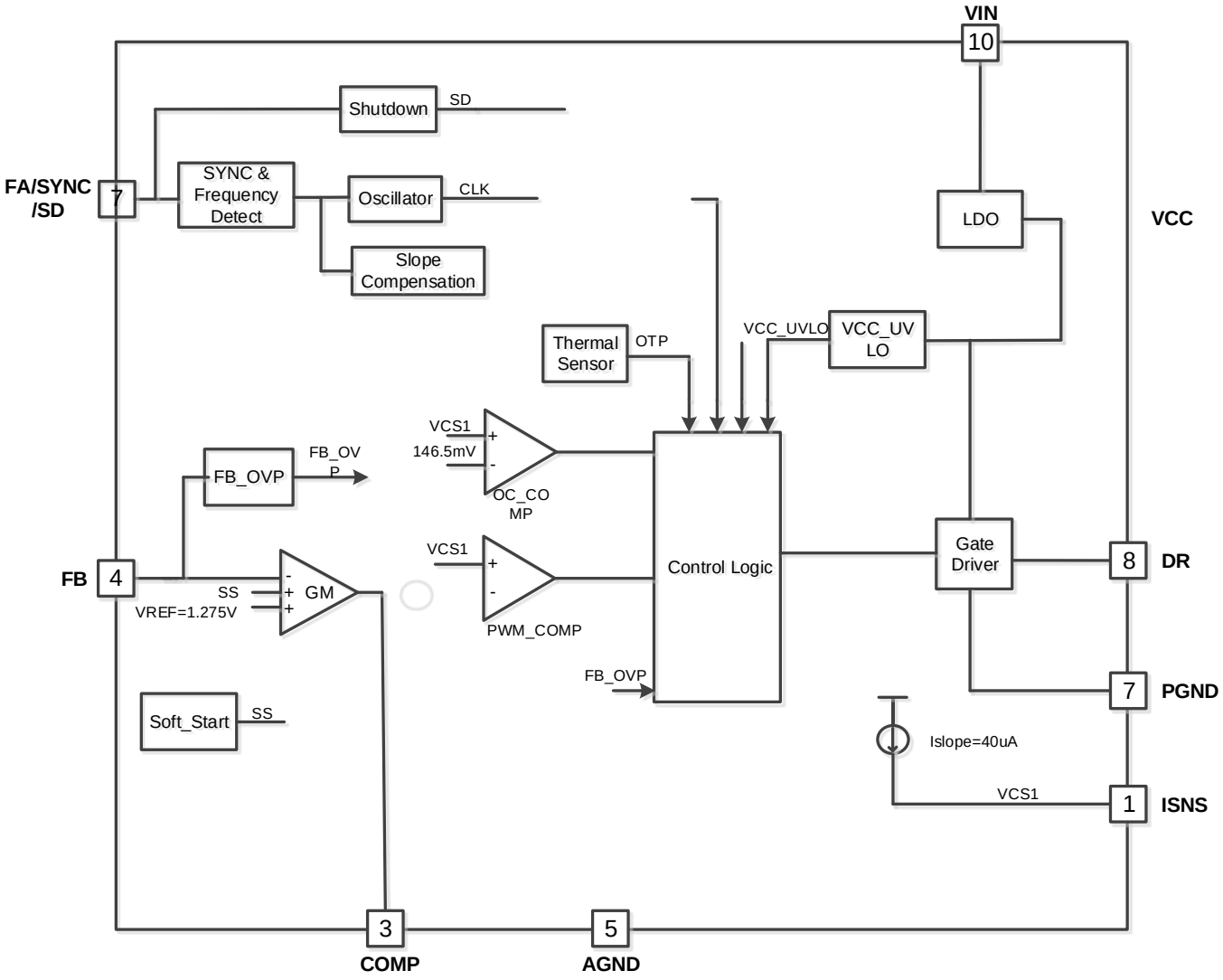


Figure 13

OPERATION

Overview

The SCT81621 device is a wide input range, non-synchronous boost controller that uses peak-current-mode control. The device can be used in boost, SEPIC, and flyback topologies.

In a typical application circuit, the peak current through the external MOSFET is sensed through an external sense resistor. The voltage across this resistor is fed into the ISNS pin. This voltage is fed into the positive input of the PWM comparator. The output voltage is also sensed through an external feedback resistor divider network and fed into the error amplifier negative input. The output of the error amplifier (COMP pin) is added to the slope compensation ramp and fed into the negative input of the PWM comparator. At the start of any switching cycle, the oscillator sets the RS latch using the switch logic block. This forces a high signal on the DR pin (gate of the external MOSFET) and the external MOSFET turns on. When the voltage on the positive input of the PWM comparator exceeds the negative input, the RS latch is reset and the external MOSFET turns off. The voltage sensed across the sense resistor generally contains spurious noise spikes. These spikes can force the PWM comparator to reset the RS latch prematurely. To prevent these spikes from resetting the latch, a blank-out circuit inside the IC prevents the PWM comparator from resetting the latch for a short duration after the latch is set. This duration is called the blanking interval and is specified as minimum on-time in the Electrical Characteristics section. Under extremely light-load or no-load conditions, the energy delivered to the output capacitor when the external MOSFET in on during the blanking interval is more than what is delivered to the load. An over-voltage comparator inside the SCT81621 prevents the output voltage from rising under these conditions. The over-voltage comparator senses the feedback (FB pin) voltage and resets the RS latch. The latch remains in reset state until the output decays to the nominal value.

The SCT81621 works at Pulse skip mode to further increase the efficiency in light load condition.

The quiescent current of SCT81621 is 415uA typical under no-load condition and no switching. Disabling the device, the typical supply shutdown current on VIN pin is 3.9

Overvoltage Protection

The SCT81621 has over voltage protection (OVP) for the output voltage. OVP is sensed at the feedback pin (FB). If at any time the voltage at the feedback pin rises to 1.36V (typ.), OVP is triggered. OVP will cause the DR pin to go low, forcing the power MOSFET off. With the MOSFET off, the output voltage will drop. The SCT81621 begins switching again when the feedback voltage reaches 1.28V (typ.).

Bias Voltage

The internal bias of the SCT81621 comes from either the internal bias voltage generator or directly from the voltage at the VIN pin. At input voltages lower than 6 V the internal IC bias is the input voltage and at voltages above 6 V the internal bias voltage generator of the SCT81621 provides the bias. The gate-driver supply voltage VCC requires an external bypass capacitor. Recommend VCC capacitance is 1μF, do not place capacitance exceeding 2.2μF. Do not bias the VCC pin by an external voltage source.

Slope Compensation Ramp

The SCT81621 uses a current mode control scheme. The main advantages of current mode control are inherent cycle-by-cycle current limit for the switch and simpler control loop characteristics. However, current mode control has a Sub-harmonic Oscillation when duty cycle is greater than 50%. To prevent the Sub-harmonic oscillations, a compensation ramp is added to the control signal.

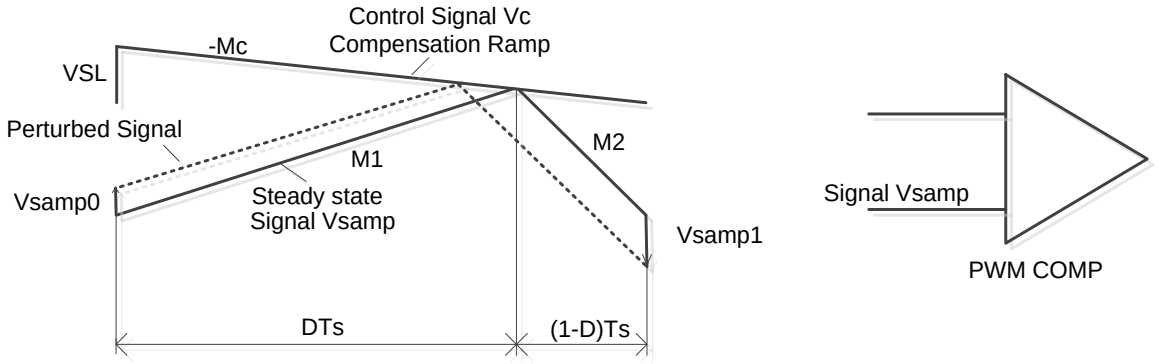


Figure14. Sub-Harmonic Oscillation for D>0.5 and Compensation Ramp to Avoid Sub-Harmonic Oscillation

The current mode control scheme samples the inductor current, IL, and compares the sampled signal, V_{samp}, to a internally generated control signal, Vc. The current sense resistor, R_{SEN}, as shown in Figure15 converts the sampled inductor current, IL, to the voltage signal, V_{samp}, that is proportional to IL such that

$$V_{samp} = I_L * R_{SEN} \quad (1)$$

Figure14 illustrate the theory why Sub-Harmonic Oscillation happen. The rising and falling slopes, M1 and -M2 respectively, of V_{samp} are also proportional to the inductor current rising and falling slopes, Mon and -Moff respectively. Where Mon is the inductor slope during the switch on-time and -Moff is the inductor slope during the switch off-time and are related to M1 and -M2 by

$$M_1 = M_{on} * R_{SEN} \quad (2)$$

$$-M_2 = -M_{off} * R_{SEN} \quad (3)$$

For the boost topology:

$$M_1 = M_{on} * R_{SEN} = Vin * R_{SEN} / L \quad (4)$$

$$M_2 = M_{off} * R_{SEN} = (Vout - Vin) * R_{SEN} / L \quad (5)$$

In Figure14, a small increase in the samp0. The effect of

$$\Delta V_{samp1} = -(\frac{M_2 - M_c}{M_1 + M_c}) * \Delta V_{samp0} \quad (6)$$

So, When No compensation ramp signal is added, which Mc is zero, then:

$$\Delta V_{samp1} = -(\frac{M_2}{M_1}) * \Delta V_{samp0} = -(\frac{D}{1-D}) * \Delta V_{samp0} \quad (7)$$

W samp1 samp0. In other words, the disturbance is divergent. So a very small perturbation in the load will cause the disturbance to increase.

After a compensation ramp is added to the control signal. To ensure that the perturbed signal converges we must maintain:

$$\left| -(\frac{M_2 - M_c}{M_1 + M_c}) \right| < 1 \quad (8)$$

The compensation ramp has been added internally in the SCT81621. The slope of this compensation ramp has been selected to satisfy most applications, and its value depends on the switching frequency. This slope can be calculated using the formula:

$$M_c = V_{SL} * F_s \quad (9)$$

V_{SL} is the amplitude of the internal compensation ramp and F_S is the controller's switching frequency.

For more flexibility, slope compensation can be increased by adding one external resistor, R_{SL}, in the ISEN's path. Figure15 shows the setup. The externally generated slope compensation is then added to the internal slope compensation of the SCT81621. When using external slope compensation, the formula for Mc becomes:

$$M_c = (V_{SL} + K * R_{SL}) * F_s \quad (10)$$

A typical value for factor K is 40 µA.

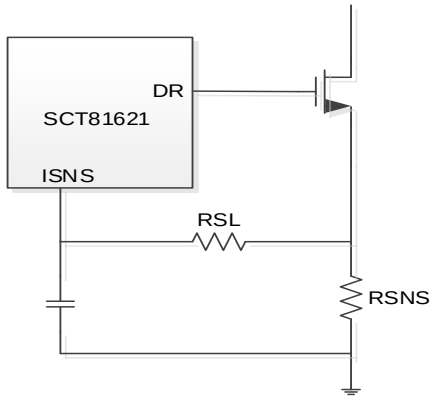


Figure15. External RSL to increase slope compensation

Adjustable Peak Current Limit

The device provides cycle-by-cycle peak current limit protection that turns off the MOSFET when the sum of the inductor current and the programmable slope compensation ramp reaches the current limit threshold. Peak inductor current limit ($I_{PEAK-CL}$) in steady state is calculated as shown in:

$$I_{PEAK\_CL} = \frac{V_{SENSE} - 40uA \times R_{SL} \times D}{R_{SNS}} \quad (11)$$

Where

V_{SENSE} is ISEN pin limiting voltage (Typ. =146.5mV)
$I_{PEAK-CL}$ is the inductor peak current limit
R_{SL} is Slope compensation resistor
D is Duty cycle
R_{SNS} is the Inductance peak current detection resistance

When overload happens, the converter cannot provide output current to satisfy loading requirement. The inductor current is clamped at over current limitation. Thus, the output voltage drops below regulated voltage with FB voltage less than internal reference voltage continuously. The internal COMP voltage ramps up to high. When COMP voltage is clamped for 64 cycles, the controller stops working. After remaining OFF for 32768 cycles the device restarts from soft starting phase. If overload or hard short condition still exists during soft-start and make COMP voltage clamped at high after soft start time and COMP still keep high for 64 cycles the device enters into turning-off mode again. When overload or hard short condition is removed, the device automatically recovers to enters normal regulating operation.

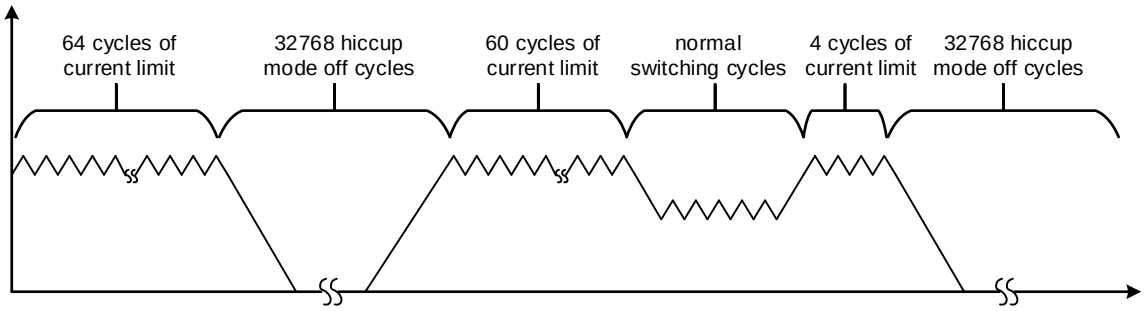


Figure16. Hiccup Mode Protection

Because D can be variable under different Vin, $I_{PEAK-CL}$ is not stable under different Vin when using external slope compensation resistor. So for an accurate peak current limit operation over the input supply voltage, SCT recommends using only the fixed slope compensation.

Output Voltage

The output voltage is set by an external resistor divider RFBT and RFBB in typical application schematic. A minimum current of typical 20uA flowing through feedback resistor divider gives good accuracy and noise covering. The value of RFBT can be calculated by Equation 12.

$$R_{FBT} = \frac{V_{OUT} - V_{REF}}{V_{REF}} \times R_{FBB} \quad (12)$$

where:

V_{REF} is the feedback reference voltage, typical 1.275V

Frequency Adjust/Shutdown/ Synchronization

The switching frequency of the SCT81621 can be adjusted between 100 kHz and 2.2 MHz using a single external resistor. This resistor must be connected between the FA/SYNC/SD pin and ground. Equation 13 can be used to estimate the frequency adjust resistor.

$$R_{FA}(K\Omega) = \frac{19700}{fsw(kHz)} - 1.177 \quad (13)$$

The SCT81621 can also be synchronized to an external clock. The external clock must be connected between the FA/SYNC/SD pin and ground, as shown in Figure 17. The frequency adjust resistor may remain connected while synchronizing a signal, therefore if there is a loss of signal, the switching frequency will be set by the frequency adjust resistor.

The FA/SYNC/SD pin also functions as a shutdown pin. If a high signal (>1.27V) appears on the FA/SYNC/SD pin over 30 S, the SCT81621 stops switching and goes into a low current mode. The total supply current of the IC reduces to 3.9 µA, typically, under these conditions.

Figure 19 and Figure 20 show an implementation of a shutdown function when operating in frequency adjust mode and synchronization mode, respectively. In frequency adjust mode, connecting the FA/SYNC/SD pin to ground forces the clock to run at a certain frequency. Pulling this pin high shuts down the IC. In frequency adjust or synchronization mode, a high signal for more than 30 µs shuts down the IC

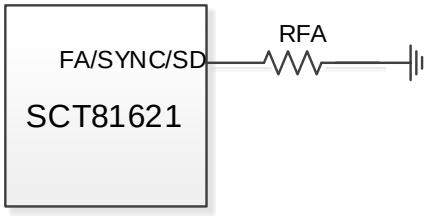


Figure17. Frequency Adjust

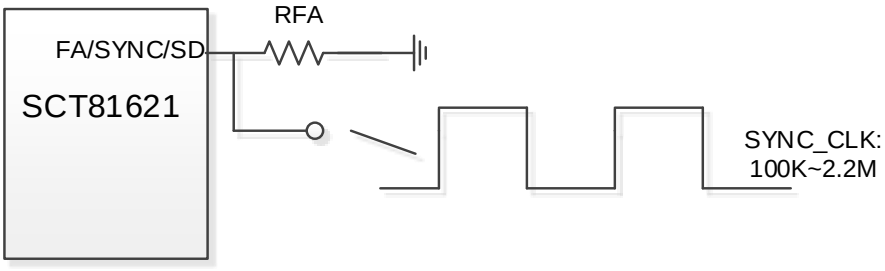


Figure18. Frequency Sync

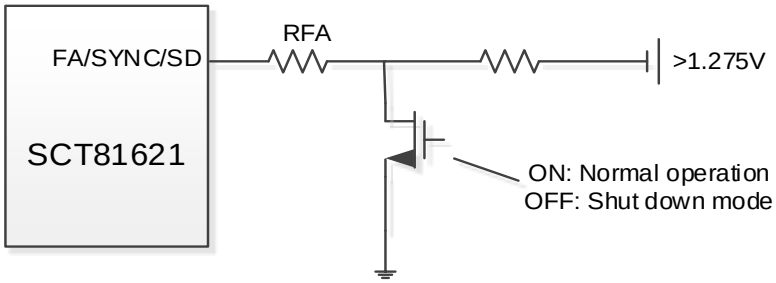


Figure19. Shutdown operation in Frequency Adjust Mode

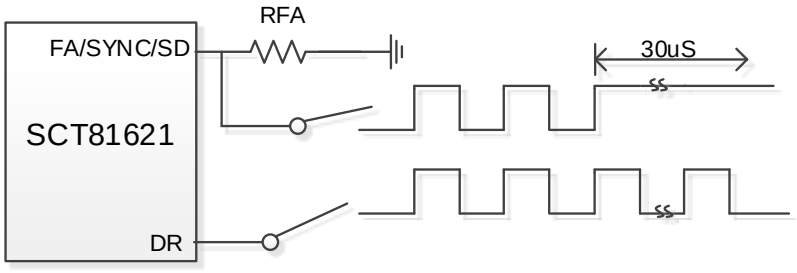


Figure20. Shutdown operation in Frequency Synchronization Mode

Enable and Under Voltage Lockout Threshold

The external UVLO resistor divider must be designed so that the voltage at the UVLO pin is greater than 1.42 V typical) when the input voltage is in the desired operating range. The values of R1 and R2 can be calculated as shown in Equation 14 and Equation 15.

$$R1 = \frac{V_{IN(ON)} - V_{IN(OFF)}}{I_{UVLO}} \quad (14)$$

where

$V_{IN(ON)}$ is the desired start-up voltage of the converter
$V_{IN(OFF)}$ is the desired turnoff voltage of the converter.

$$R2 = R1 * \frac{V_{UVLOEN}}{V_{IN(ON)} - V_{UVLOEN}} \quad (15)$$

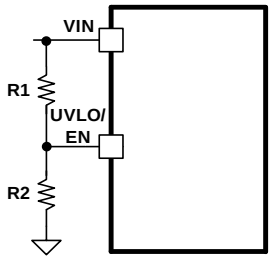


Figure21. System UVLO Resistor Divider

Frequency Spread Spectrum

To reduce EMI, the device implements Frequency Spread Spectrum (FSS). The FSS circuitry shifts the switching freq n5Q-9(g c)-86o ret(g c)-86o ret2 0 612 792 r86o 5 Gþlements FSpan <</MCID 16/Lang g g5(tr)-2(y)-5> BDC q5oc9 4 g-2(y

APPLICATION INFORMATION

Typical Application (Boost)

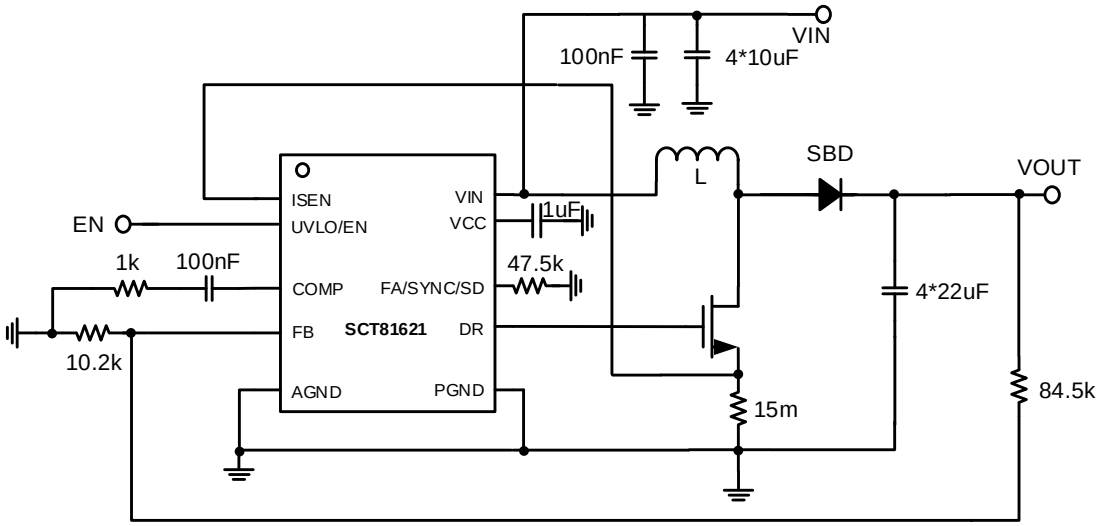


Figure 22. Application Schematic, 3V to 11V, 2A Boost Regulator at 400kHz

Design Parameters

Design Parameters	Example Value
Input Voltage	5V Normal 3V to 11V
Output Voltage	12V
Maximum Output Current	3A
Switching Frequency	400 KHz
Output voltage ripple (peak to peak)	75mV (Load=2A)

The total power dissipation of MOSFET includes conduction loss as shown in the first term and switching loss as shown in the second term. The total power dissipation should be within package thermal ratings.

Output Diode Selection

Observation of the boost converter circuit shows that the average current through the diode is the average load current, and the peak current through the diode is the peak current through the inductor. The diode should be rated to handle more than its peak current. The peak diode current can be calculated using Equation 26.

$$I_{D(PEAK)} = \frac{I_{OUT}}{(1-D)} + \Delta I_L \quad (26)$$

Thermally the diode must be able to handle the maximum average current delivered to the output. The peak reverse voltage for boost converters is equal to the regulated output voltage. The diode must be capable of handling this voltage. To improve efficiency, a low forward drop schottky diode is recommended.

Application Waveforms

Vin=5V, Vout=12V, unless otherwise noted

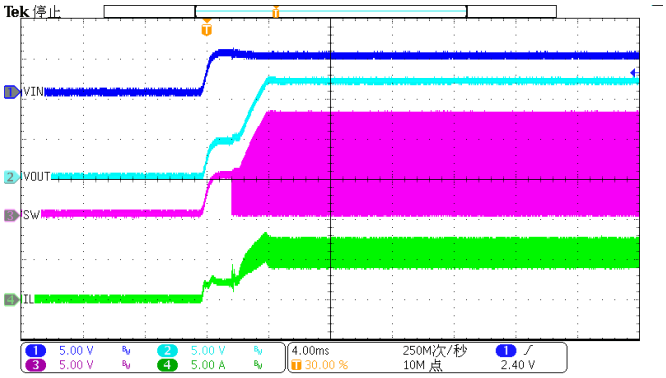


Figure 23. Power up(Iload=2A)

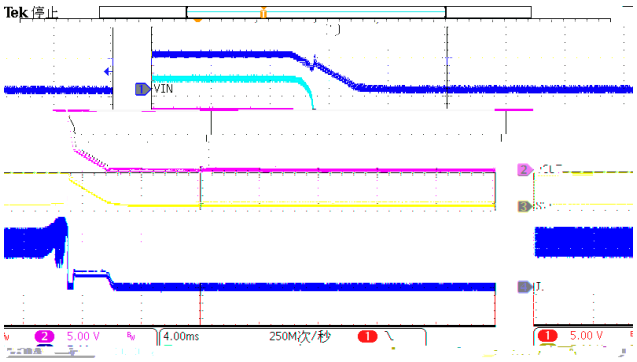


Figure 24. Power down(Iload=2A)

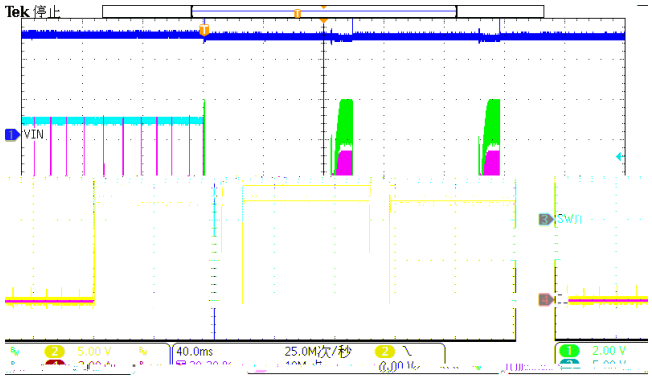


Figure 25. Over current protection (Iload=5A)

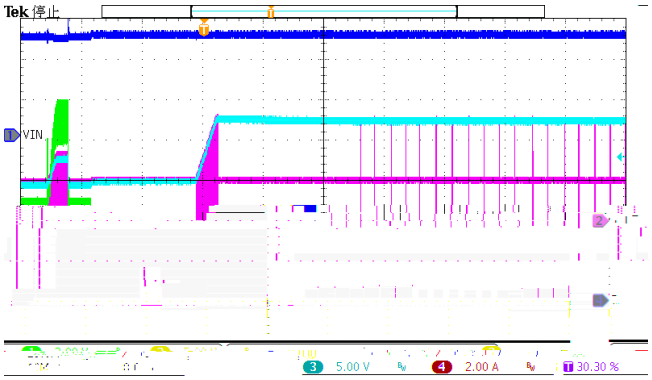


Figure 26. Over current recovery (Iload=5A)

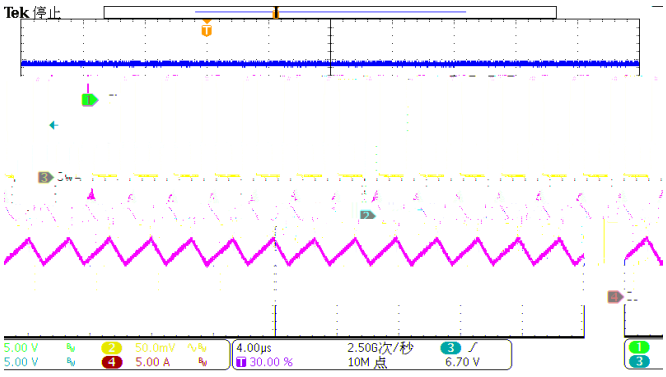


Figure 27. Steady-state (Iload=2A)

Figure 28. Sync Frequency

APPLICATION INFORMATION

Typical Application(Sepic)

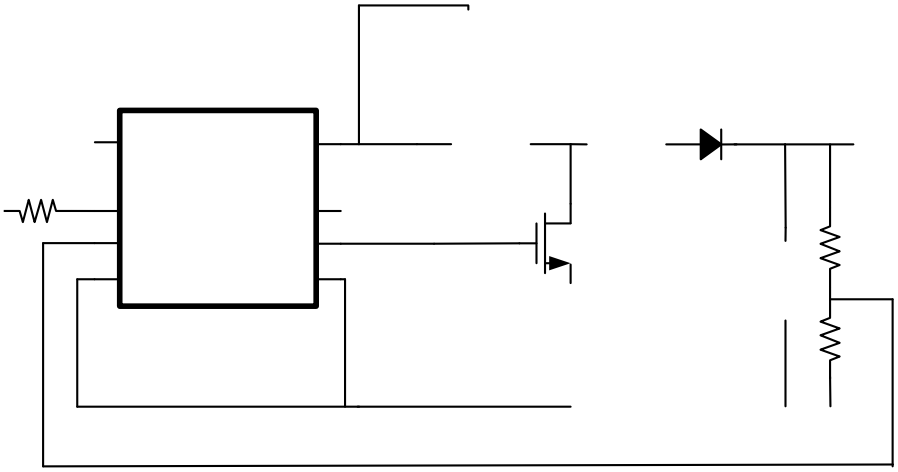


Figure 29. Application Schematic, 5V to 50V, 2A Sepic Regulator at 400kHz

Design Parameters

Design Parameters	Example Value

The total power dissipation of MOSFET includes conduction loss as shown in the first term and switching loss as shown in the second term. The total power dissipation should be within package thermal ratings.

Output Diode Selection

The diode at the output side must withstand the reverse voltage when the MOSFET is turned-on. The peak reverse voltage is given by:

$$V_{D\_PEAK} = V_{IN\_MAX} + V_{O\_MAX} \quad (37)$$

The diode should also be capable to flow switch peak current I_{Q_PEAK}.

The power dissipation of the diode is equal to the forward voltage drop multiplies output current. Schottky diodes are recommended here to minimize the power loss.

Coupling Capacitor Selection

For ceramic capacitors with low-ESR, the peak to peak voltage ripple on coupling capacitor is estimated by:

$$\Delta V_{CS} = \frac{I_O \times D_{MAX}}{C_S \times f_{SW}} \quad (38)$$

The maximum voltage across the coupling capacitor is maximum input voltage. The voltage rating of the coupling capacitor must be greater than it.

The RMS current of coupling capacitor is given by:

$$I_{CS\_RMS} = I_O \times \sqrt{\frac{V_O + V_D}{V_{IN\_MIN}}} \quad (39)$$

There is a large RMS current through coupling capacitor relative to output power. Ensure the coupling capacitor can withstand it with good heat generation to have proper thermal performance.

Input Capacitor Selection

The SEPIC has an inductor at input side thus the input current is continuous and triangular. The RMS current flowing through the input capacitor is given by:

$$I_{IN\_RMS} = \frac{\Delta I_{L1}}{\sqrt{12}} \quad (40)$$

Since input current ripple is relative low, the capacitance would be not too critical. While 100 F in total or higher value is strongly recommended in order to provide stable input supply.

Output Capacitor Selection

Similar to boost converter, the SEPIC output capacitor suffers large current ripple. The capacitance must be enough to provide the load current. The maximum voltage ripple in the output capacitor is:

$$\Delta V_{OUT} = \frac{I_O \times D_{MAX}}{C_{OUT} \times f_{SW}} + ESR \times \left(I_{L1\_PEAK} + I_{L2\_PEAK} \right) \quad (41)$$

Assuming ceramic capacitors are used here and ESR can be ignored, the output capacitor is given by:

$$C_{OUT} \geq \frac{I_O \times D_{MAX}}{\Delta V_{OUT} \times f_{SW}} \quad (42)$$

The output capacitor must have an enough RMS current rating to handle the maximum RMS current in the output capacitor, calculated by:

$$I_{COUT\_RMS} = I_O \times \sqrt{\frac{D_{MAX}}{1 - D_{MAX}}} \quad (43)$$

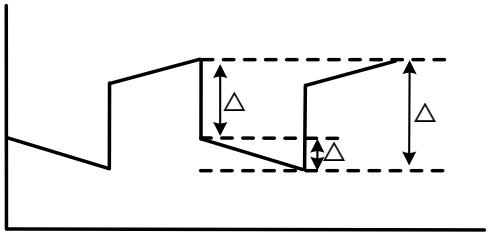


Figure 30. Output Voltage Ripple

Application Waveforms

Vin=5V, Vout=12V, unless otherwise noted

Figure 31. Power up(Iload=2A)

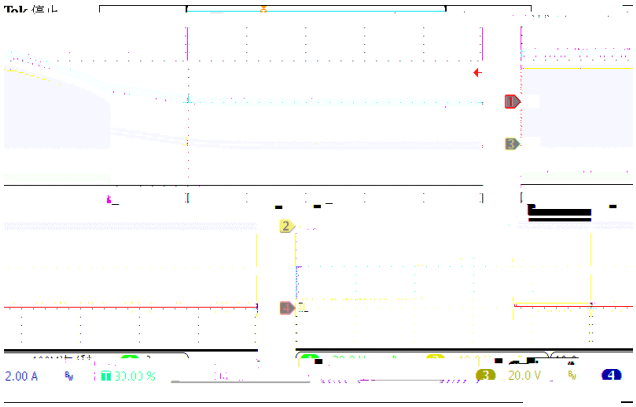


Figure 32. Power down(Iload=2A)

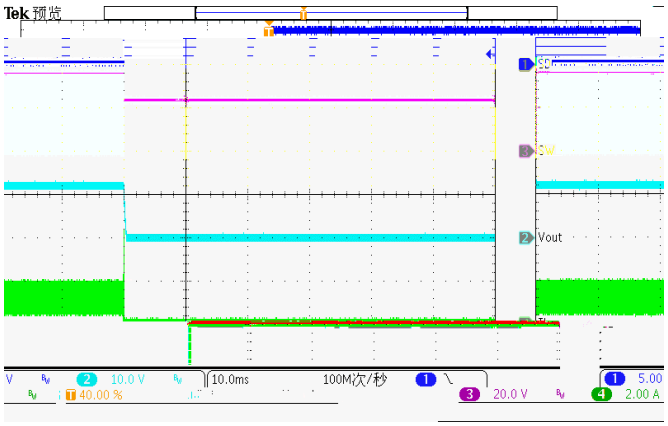


Figure 33. Shutdown entry

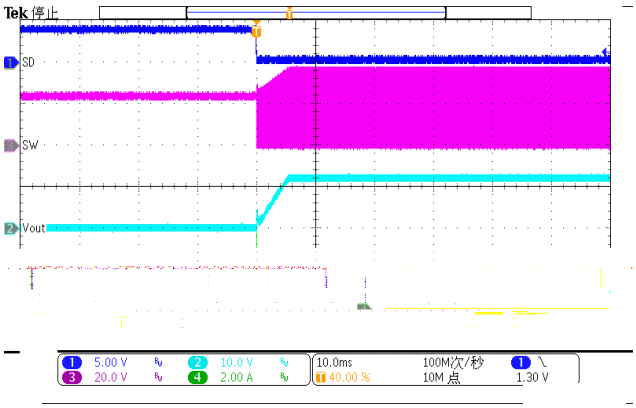


Figure 34. Shutdown remove

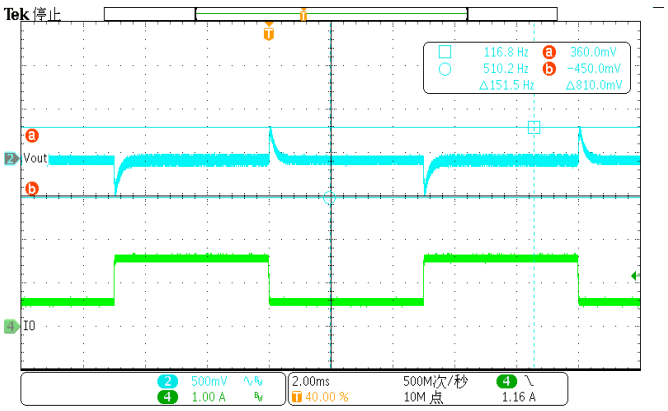


Figure 35. LoadTrans (Iload=0.5A-1.5A)

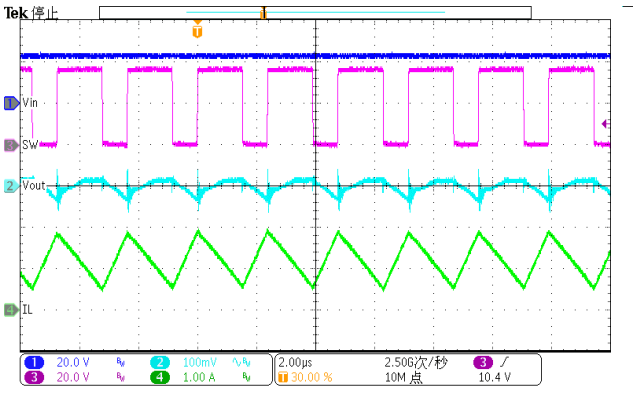


Figure 36. steady-state (Iload=2A)

Layout Guideline

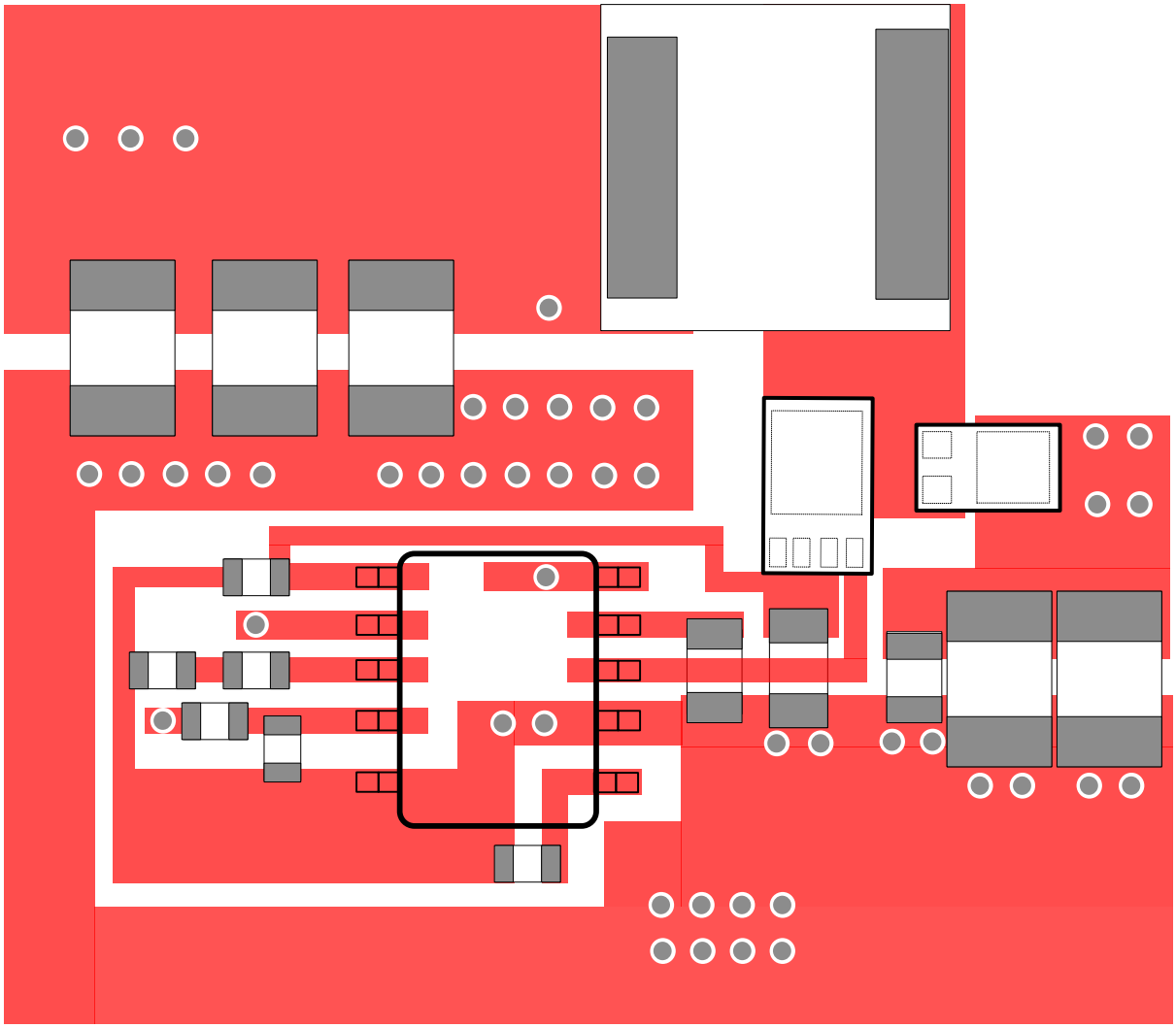
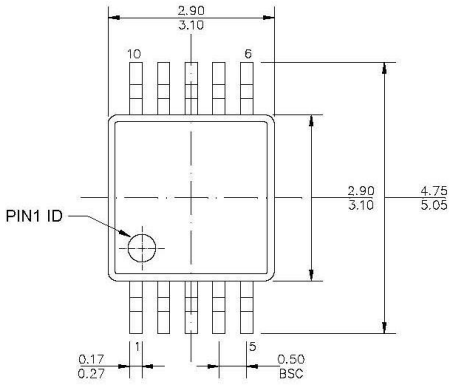
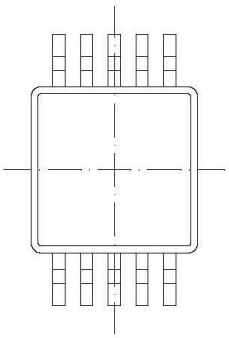


Figure 37. Boost PCB Layout

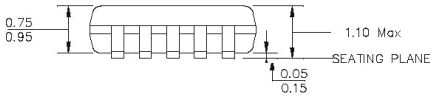
PACKAGE INFORMATION



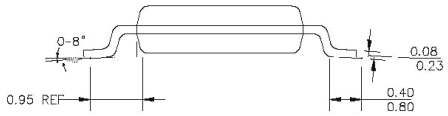
TOP VIEW



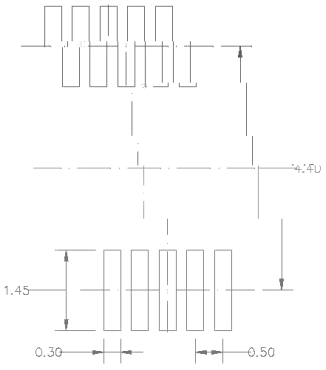
BOTTOM VIEW



FRONT VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN

NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR.
3) DRAWING MEETS JEDEC MO-187 VARIATION BA.
4) DRAWING IS NOT TO SCALE.

TAPE AND REEL INFORMATION